



DMPH3010LPS

Product Summary

V _{(BR)DSS}	R _{DS(ON)} Max	I _D T _C = +25°C
-30V	$7.5 \text{m}\Omega @ V_{\text{GS}} = -10 \text{V}$	-60A
-30 V	$10m\Omega @ V_{GS} = -4.5V$	-50A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- **DC-DC Converters**
- Power Management Functions
- Analog Switch

175°C P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature **Environments**
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

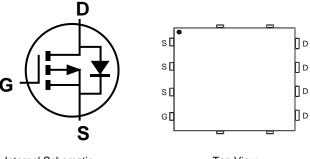
- Case: POWERDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3)
- Weight: 0.097 grams (Approximate)



Pin1

Top View

Bottom View



Internal Schematic

) | | = Manufacturer's Marking H3010LS = Product Type Marking Code

YYWW = Date Code Marking YY = Year (ex: 15 = 2015)

WW = Week (01 to 53)

Top View Pin Configuration

ΠD

ΠD

Πр

Ordering Information (Note 4)

Part Number	Case	Packaging
DMPH3010LPS-13	POWERDI [®] 5060-8	2,500 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

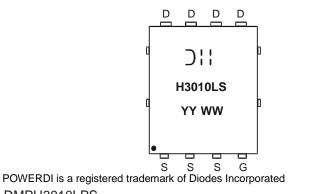
and Lead-free

Notes:

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



DMPH3010LPS Document number: DS37129 Rev. 1 - 2



NEW PRODUCT

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-30	V		
Gate-Source Voltage			V _{GSS}	±20	V
	Steady State	T _C = +25°C T _C = +100°C	I _D	-60 -40	А
Continuous Drain Current (Note 6), $V_{GS} = -10V$	Steady State	T _A = +25°C T _A = +100°C	ID	-15 -11	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			IDM	-100	A
Maximum Body Diode Continuous Current (Note 6)			Is	-3.5	A
Avalanche Current (Note 7), L = 0.1mH			I _{AS}	-47	A
Avalanche Energy (Note 7), L = 0.1mH			EAS	113	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	98	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	58	°C/W
Thermal Resistance, Junction to Case		R _{θJC}	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

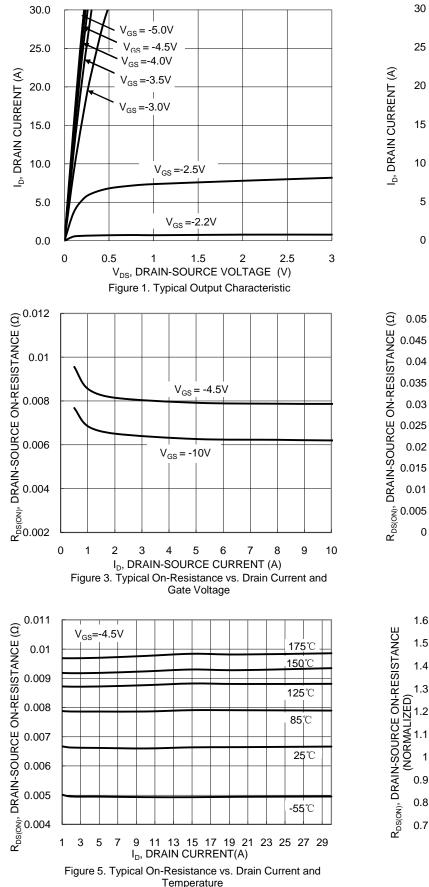
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30			V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_		-1.0	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	-1.1	-1.6	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance			5.7	7.5	mΩ	$V_{GS} = -10V, I_D = -10A$	
	R _{DS(ON)}		7.2	10	11122	$V_{GS} = -4.5V, I_D = -10A$	
Diode Forward Voltage	V _{SD}		-0.65	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	6807	—	pF		
Output Capacitance	Coss	_	988		pF	V _{DS} = -15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss		647	_	pF	1 - 1.00012	
Gate Resistance	Rg		6.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg		66	_	nC		
Total Gate Charge (V _{GS} = -10V)	Qg		139	_	nC	Vps = -15V. lp = -10A	
Gate-Source Charge	Q _{gs}		19.1	_	nC	$v_{DS} = -15v, I_D = -10A$	
Gate-Drain Charge	Q _{gd}		21.7	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	9.0		ns		
Turn-On Rise Time	t _R	_	10.5		ns		
Turn-Off Delay Time	t _{D(OFF)}	_	255	—	ns	$R_G = 6\Omega, I_D = -1A$	
Turn-Off Fall Time	tF	_	95		ns		
Body Diode Reverse Recovery Time	t _{RR}	_	27	—	ns	I _F = -10A, di/dt = -100A/µs	
Body Diode Reverse Recovery Charge	Q _{RR}	—	21	—	nC	I _F = -10A, di/dt = -100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

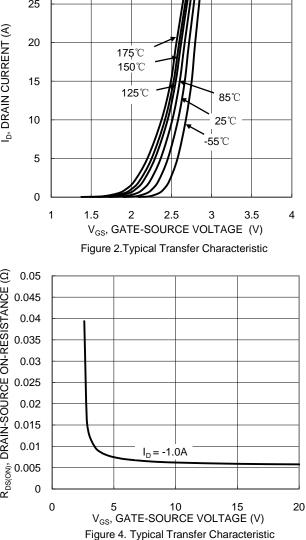
7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J =+ 25°C.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.



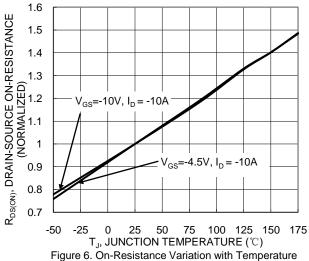
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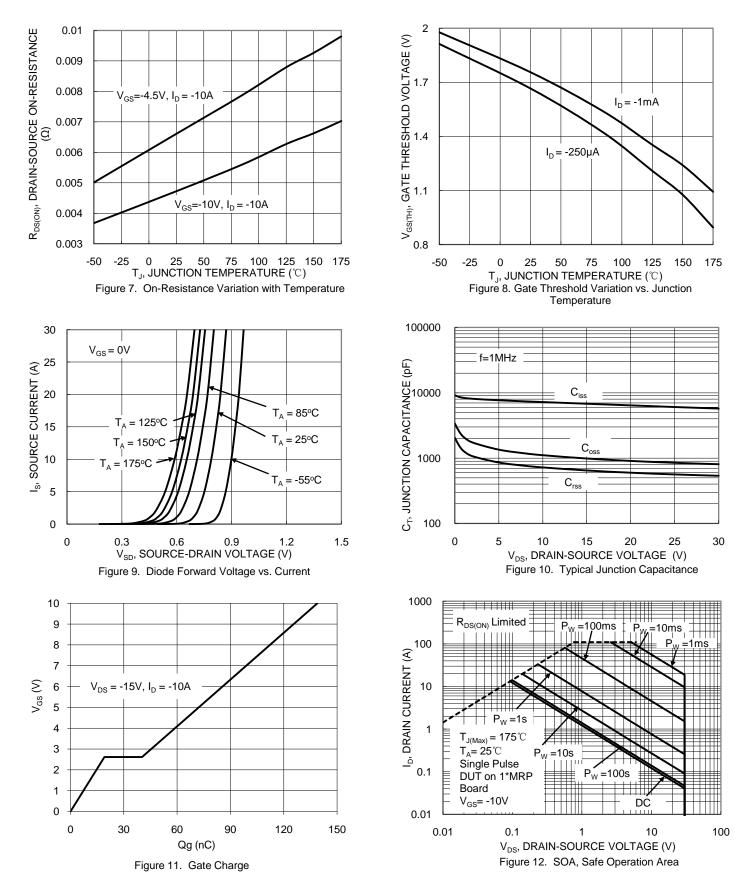
V_{DS}= -5.0V



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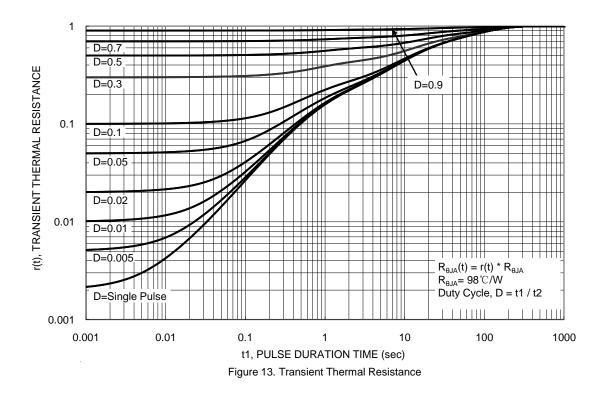
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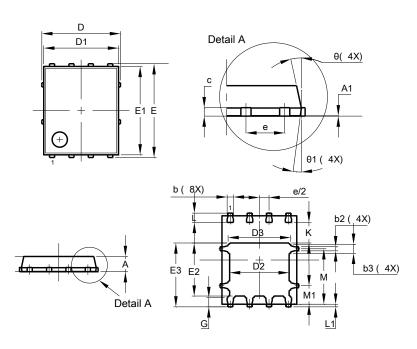




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

POWERDI[®]5060-8

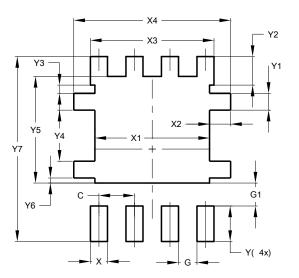


POWERDI [®] 5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	_	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D	1	5.15 BSC	;	
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
Е	6	6.15 BSC	;	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е		1.27 BSC	;	
G	0.51	0.71	0.61	
K	0.51	-	-	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
М	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10º	12º	11º	
Θ1	6º	8º	7°	
All	All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

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Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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